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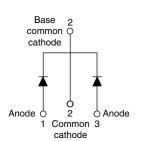


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Vishay Semiconductors

# Schottky Rectifier, 2 x 30 A

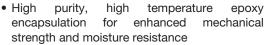




PRODUCT SUMMARY						
Package	TO-220AB					
I <sub>F(AV)</sub>	2 x 30 A					
$V_R$	35 V, 40 V, 45 V					
V <sub>F</sub> at I <sub>F</sub>	0.57 V					
I <sub>RM</sub> max.	40 mA at 125 °C					
T <sub>J</sub> max.	175 °C					
Diode variation	Common cathode					
E <sub>AS</sub>	27 mJ					

#### **FEATURES**

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

### **DESCRIPTION**

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	IBOL CHARACTERISTICS VALUES UNITS								
I <sub>F(AV)</sub>	Rectangular waveform (per device)	60	Α						
V <sub>RRM</sub>		35 to 45	V						
I <sub>FRM</sub>	T <sub>C</sub> = 142 °C (per leg)	60	^						
I <sub>FSM</sub>	t <sub>p</sub> = 5 µs sine	2600	A						
V <sub>F</sub>	30 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.57	V						
TJ	Range	- 65 to 175	°C						

VOLTAGE RATINGS										
PARAMETER	SYMBOL	VS- 61CTQ035PbF	VS- 61CTQ035-N3	VS- 61CTQ040PbF	VS- 61CTQ040-N3	VS- 61CTQ045PbF	VS- 61CTQ045-N3	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>									
Maximum working peak reverse voltage	V <sub>RWM</sub>	35	35	40	40	45	45	V		

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum average	per leg		T 140 00 material V				30	
forward current per device		I <sub>F(AV)</sub>	$I_C = 142 \text{ C}, \text{ rated } V_R$	T <sub>C</sub> = 142 °C, rated V <sub>R</sub>		A		
Peak repetitive forward current per leg		I <sub>FRM</sub>	Rated $V_R$ , square wave, 20 kHz, $T_C$ = 142 °C		60			
Maximum peak one cycle non-repetitive surge current per leg		l=a	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	2600			
		I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	350			
Non-repetitive avalanche energy per leg		E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 4 A, L = 3.4 mH		27	mJ		
Repetitive avalanche current per leg		I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		4	Α		



# VS-61CTQ...PbF Series, VS-61CTQ...-N3 Series

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS			UNITS		
Maximum forward voltage drop		30 A	T <sub>.1</sub> = 25 °C	0.57	0.61			
	V <sub>FM</sub> <sup>(1)</sup>	60 A	1j=25 C	0.72	0.76	٧		
		30 A	T 105 %C	0.53	0.57			
		60 A	T <sub>J</sub> = 125 °C	0.70	0.74			
Maximum instantaneous reverse current	I <sub>RM</sub>	T <sub>J</sub> = 25 °C	Rated DC voltage	0.06	1	mA		
Maximum instantaneous reverse current		T <sub>J</sub> = 125 °C	hated DC voltage	21	40	IIIA		
Maximum junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal range 100 kHz to 1 MHz) 25 °C		19	00	pF		
Typical series inductance	L <sub>S</sub>	Measured from top of terminal to mounting plane			.0	nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10	000	V/µs		

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and stora temperature range	age	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C			
Maximum thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	1.2	°C/W			
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	C/ VV			
Approximate weight				2	g			
Approximate weight				0.07	OZ.			
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf · cm			
Mounting torque — maximum			Non-lubricated threads		(lbf · in)			
Marking device				61CTQ035				
			Case style TO-220AB		Q040			
				61CTQ045				

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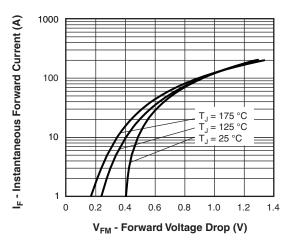


Fig. 1 - Maximum Forward Voltage Drop Characteristics

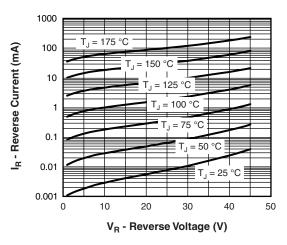


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

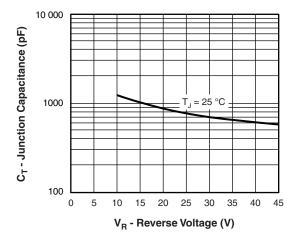


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

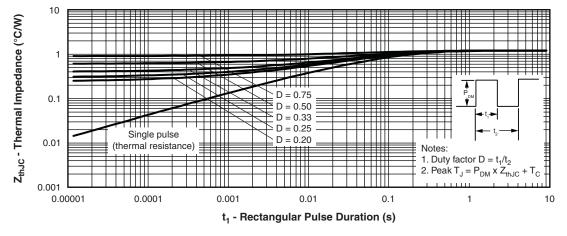


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



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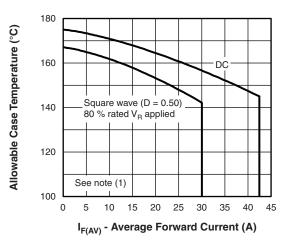


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

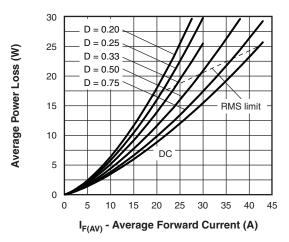


Fig. 6 - Forward Power Loss Characteristics

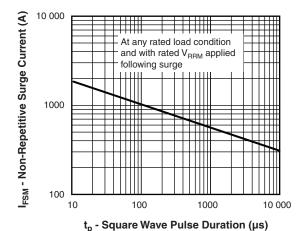


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

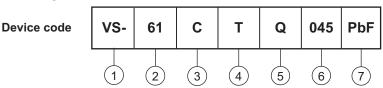
#### Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = 80 \text{ \% rated } V_R \\ \end{array}$ 

# VS-61CTQ...PbF Series, VS-61CTQ...-N3 Series

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### **ORDERING INFORMATION TABLE**



1 - Vishay Semiconductors product

2 - Current rating (60 = 60 A)

Circuit configuration

C = Common cathode

4 - Package

T = TO-220

5 - Schottky "Q" series

035 = 35 V

Voltage ratings

040 = 40 V 045 = 45 V

7 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-61CTQ035PbF	50	1000	Antistatic plastic tube					
VS-61CTQ035-N3	50	1000	Antistatic plastic tube					
VS-61CTQ040PbF	50	1000	Antistatic plastic tube					
VS-61CTQ040-N3	50	1000	Antistatic plastic tube					
VS-61CTQ045PbF	50	1000	Antistatic plastic tube					
VS-61CTQ045-N3	50	1000	Antistatic plastic tube					

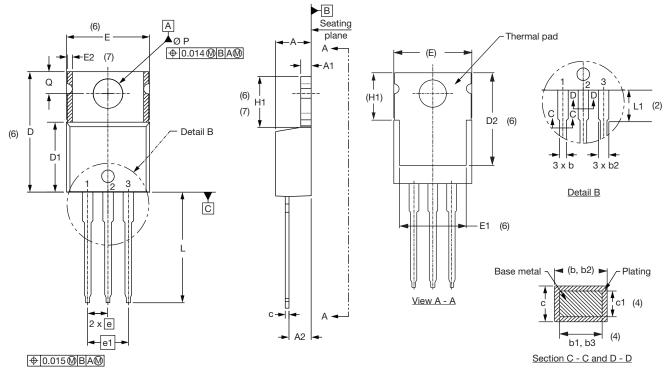
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95222</u>					
Dort marking information	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			



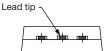
## Vishay Semiconductors

### **TO-220AB**

### **DIMENSIONS** in millimeters and inches



### Lead assignments



- <u>Diodes</u>
- 1. Anode/open
- 2. Cathode
- 3. Anode

### Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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